



**THE DATASHEET OF
DMP2088LCP3-7**



OBsolete – PART DISCONTINUED

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D T _A = +25°C
-20V	88mΩ @ V _{GS} = -8V	-2.9A
	105mΩ @ V _{GS} = -4.5V	-1.8A

Description

This new generation MOSFET is designed to minimize the footprint in handheld and mobile applications. It can be used to replace many small signals MOSFET with as really small footprint.

Applications

- Battery management
- Load switches
- Battery protections
- Handheld and mobile applications

Features and Benefits

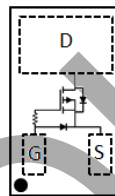
- Low Q_g & Q_{gd}
- Small Footprint
- Low Profile 0.30mm Height
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- Halogen and Antimony Free. “Green” Device (Note 3)**
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](#) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>

Mechanical Data

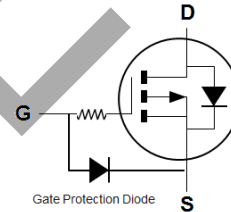
- Package: X2-DSN1006-3
- Terminal Connections: See Diagram Below
- Terminals: Finish – Matte Tin Annealed over Copper Pillar [Ⓢ]



X2-DSN1006-3



Top View



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Package	Packing	
		Qty.	Carrier
DMP2088LCP3-7	X2-DSN1006-3	3,000	Tape & Reel

- Notes:
- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 - See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 - For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



B = Product Type Marking Code
 YM = Date Code Marking
 Y or \bar{Y} = Year (ex: J = 2022)
 M or \bar{M} = Month (ex: 9 = September)

Date Code Key

Year	2015	...	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	C	...	J	K	L	M	N	O	P	R	S	T

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-20	V
Gate-Source Voltage			V _{GSS}	-12	V
Continuous Drain Current (Note 5) V _{GS} = -8V	Steady State	T _A = +25°C	I _D	-2.9	A
		T _A = +70°C		-2.4	
Continuous Drain Current (Note 5) V _{GS} = -4.5V	Steady State	T _A = +25°C	I _D	-1.8	A
		T _A = +70°C		-1.4	
Pulsed Drain Current (Note 6)			I _{DM}	-15	A
Human Body Model (HBM)			V(ESD)	4	kV

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 7)	P _D	0.57	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 7)	R _{θJA}	217	°C/W
Power Dissipation (Note 5)	P _D	1.13	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5)	R _{θJA}	110	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	-20	—	—	V	V _{GS} = 0V, I _D = -250μA
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	—	—	-100	nA	V _{DS} = -16V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	—	—	-50	nA	V _{GS} = -12V, V _{DS} = 0V
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(TH)}	-0.7	-1.0	-1.2	V	V _{DS} = V _{GS} , I _D = -250μA
Static Drain-Source On-Resistance	R _{DS(ON)}	—	73	88	mΩ	V _{GS} = -8V, I _D = -0.5A
		—	90	105		V _{GS} = -4.5V, I _D = -0.5A
		—	143	174		V _{GS} = -2.5V, I _D = -0.5A
		—	266	750		V _{GS} = -1.8V, I _D = -0.1A
		—	—	—		—
Forward Transfer Admittance	Y _{fs}	—	3.4	—	S	V _{DS} = -10V, I _D = -0.5A
Diode Forward Voltage	V _{SD}	—	-0.75	-1.0	V	V _{GS} = 0V, I _S = -0.5A
Reverse Recovery Charge	Q _R	—	1.0	—	nC	V _{DD} = -10V, I _F = -1A,
Reverse Recovery Time	t _{RR}	—	5.7	—	ns	di/dt = 100A/μs
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C _{iss}	—	121	160	pF	V _{DS} = -10V, V _{GS} = 0V, f = 1.0MHz
Output Capacitance	C _{oss}	—	66	100		
Reverse Transfer Capacitance	C _{rss}	—	4.3	8		
Series Gate Resistance	R _G	9	18	36	Ω	f = 1MHz, V _{GS} = 0V, V _{DS} = 0V
Total Gate Charge	Q _g	—	1.1	1.5	nC	V _{GS} = -4.5V, V _{DS} = -10V, I _D = -0.5A
Gate-Source Charge	Q _{gs}	—	0.17	—		
Gate-Drain Charge	Q _{gd}	—	0.22	—		
Gate Charge at V _{TH}	Q _{g(th)}	—	0.12	—		
Turn-On Delay Time	t _{D(ON)}	—	6.3	12	ns	V _{DS} = -10V, V _{GS} = -4.5V, R _G = 2Ω, I _D = -0.5A
Turn-On Rise Time	t _r	—	2.8	—		
Turn-Off Delay Time	t _{D(OFF)}	—	17	34		
Turn-Off Fall Time	t _f	—	6	—		

- Notes:
- Device mounted on FR-4 material with 1inch² (6.45cm²), 2oz. (0.071mm thick) Cu.
 - Repetitive rating, pulse width limited by junction temperature.
 - Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.
 - Short duration pulse test used to minimize self-heating effect.
 - Guaranteed by design. Not subject to production testing.

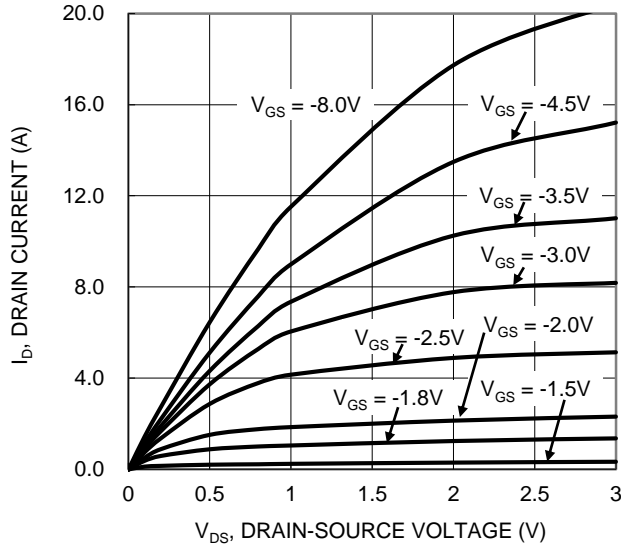


Figure 1. Typical Output Characteristic

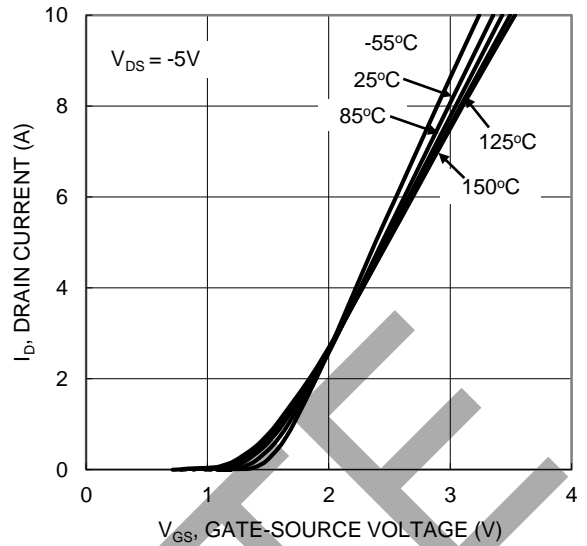


Figure 2. Typical Transfer Characteristic

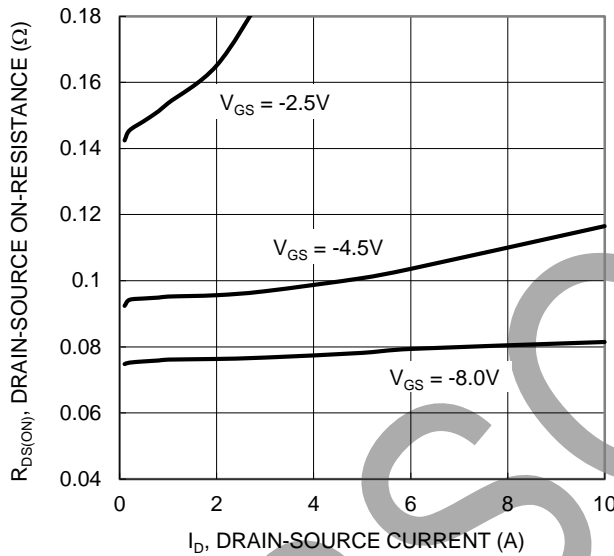


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

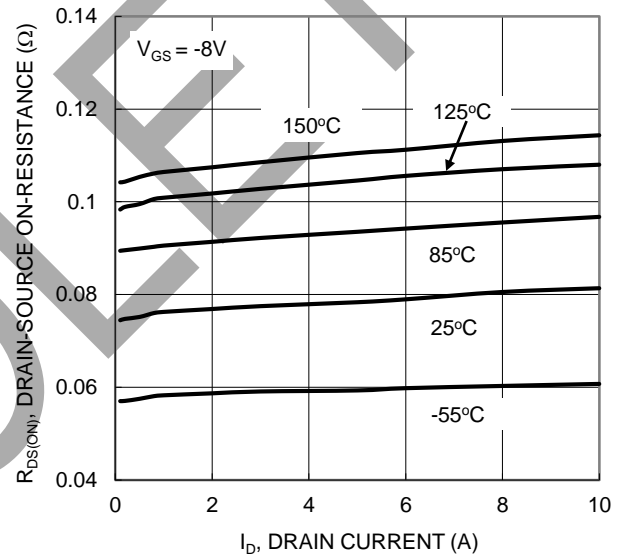


Figure 4. Typical On-Resistance vs. Drain Current and Junction Temperature

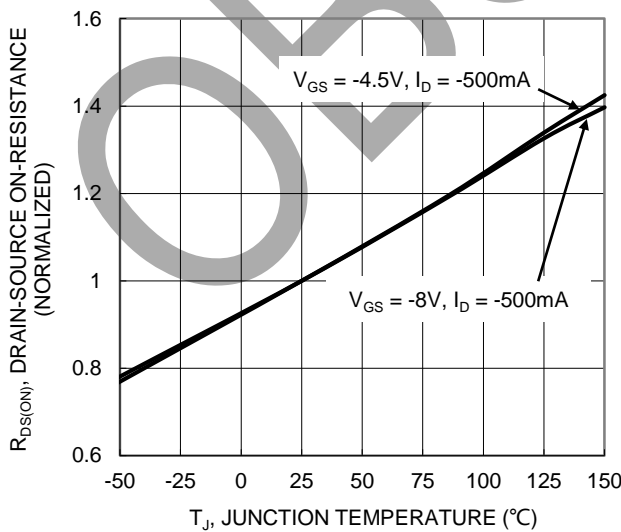


Figure 5. On-Resistance Variation with Junction Temperature

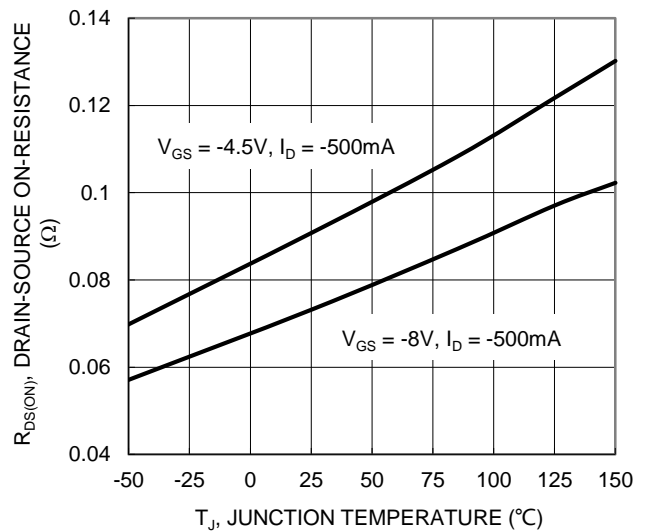


Figure 6. On-Resistance Variation with Junction Temperature

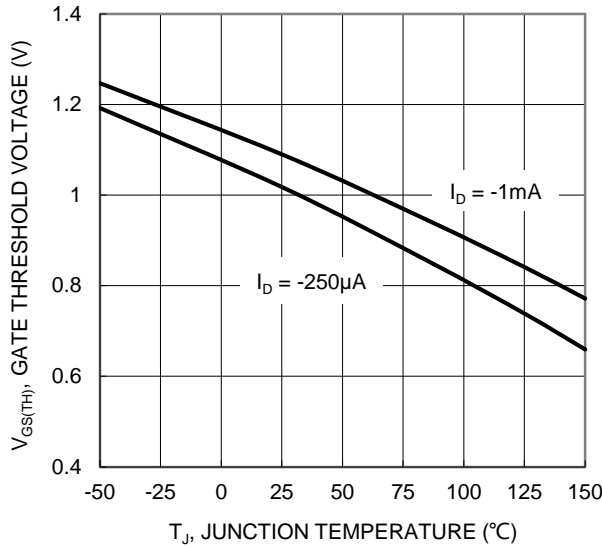


Figure 7. Gate Threshold Variation vs. Junction Temperature

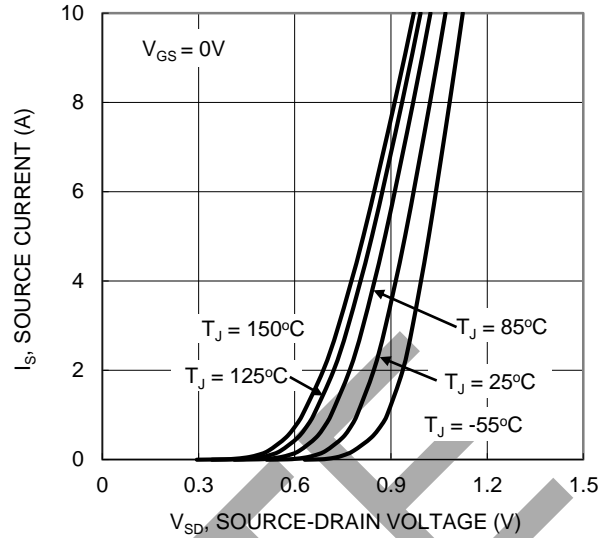


Figure 8. Diode Forward Voltage vs. Current

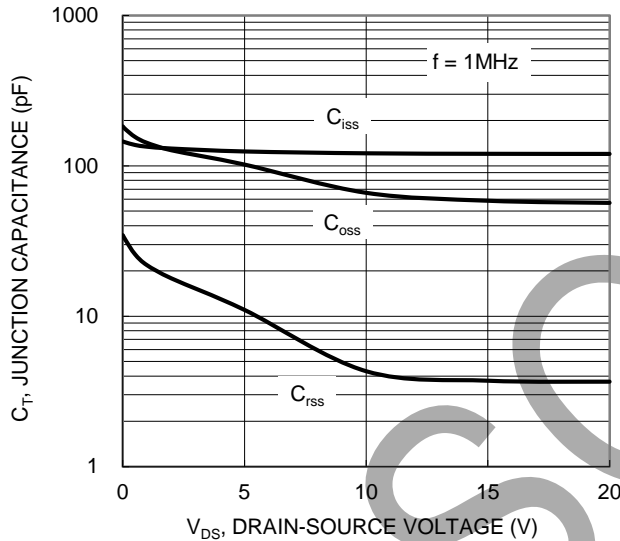


Figure 9. Typical Junction Capacitance

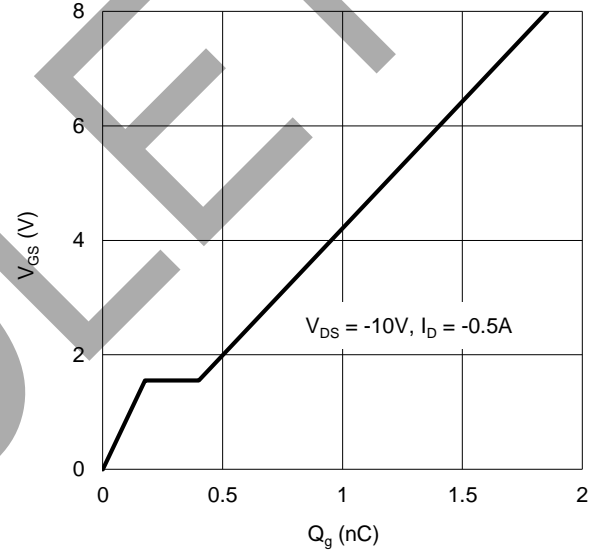


Figure 10. Gate Charge

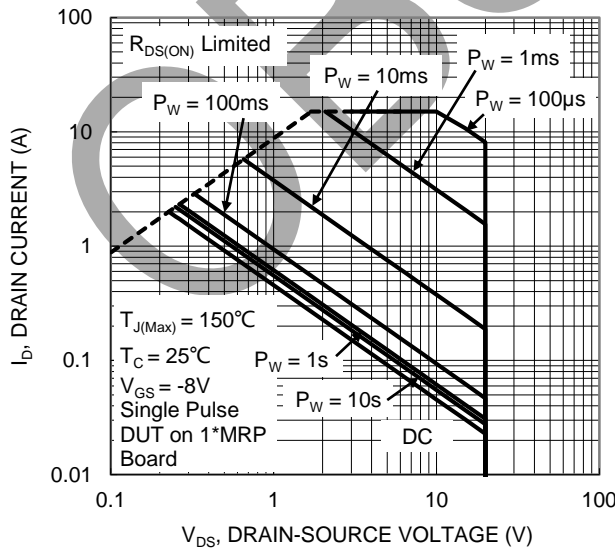


Figure 11. SOA, Safe Operation Area

OBSOLETE - PART DISCONTINUED

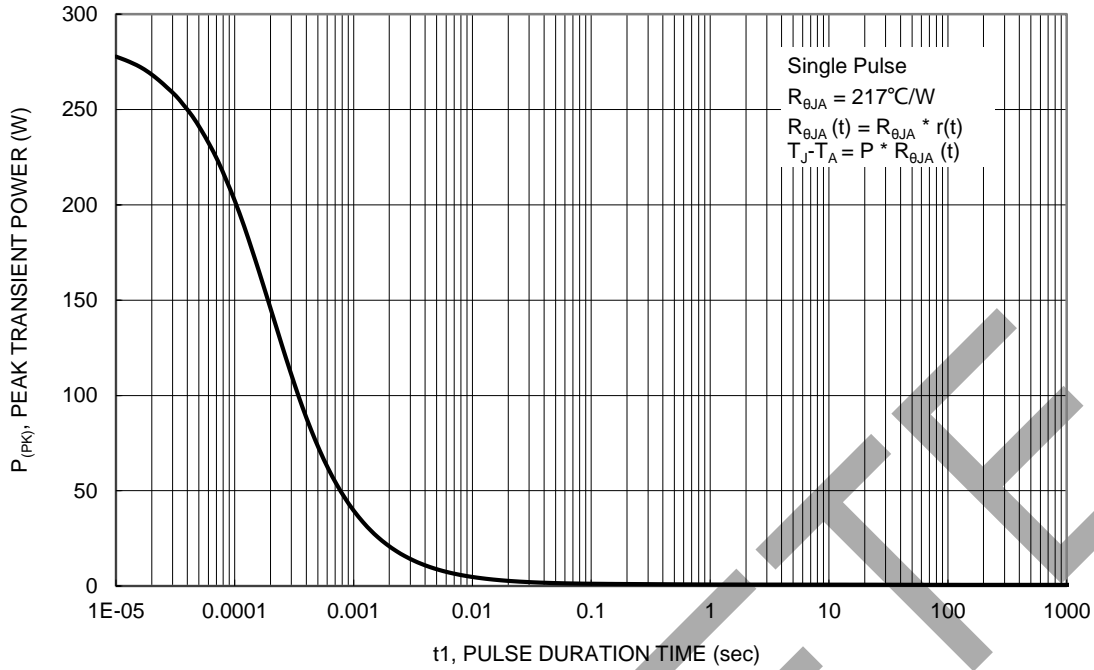


Figure 12. Single Pulse Maximum Power Dissipation

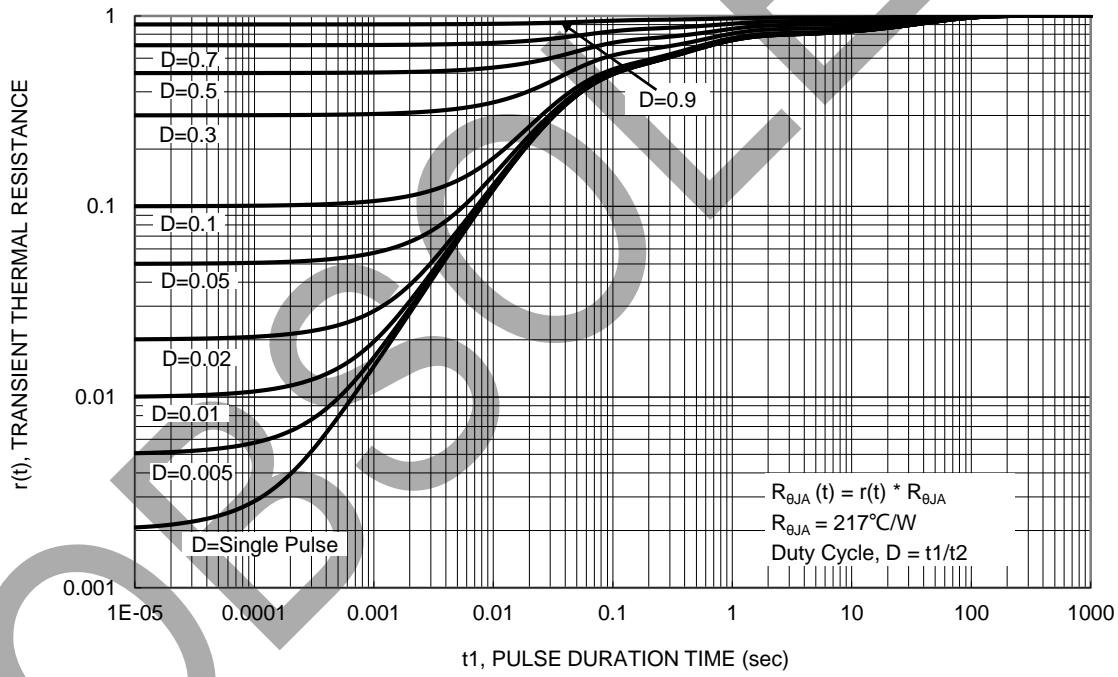
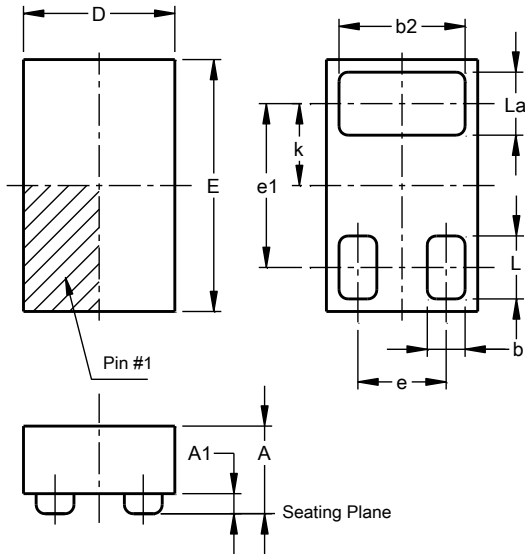


Figure 13. Transient Thermal Resistance

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

X2-DSN1006-3



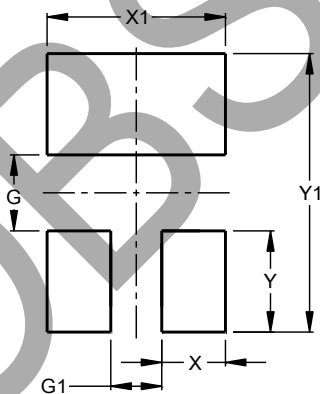
X2-DSN1006-3			
Dim	Min	Max	Typ
A	--	0.348	0.32
A1	--	--	0.08
b	0.14	0.16	0.15
b2	0.49	0.51	0.50
D	0.56	0.64	0.60
E	0.96	1.04	1.00
e	--	--	0.35
e1	--	--	0.65
k	--	--	0.325
L	0.21	0.29	0.25
La	0.21	0.29	0.25

All Dimensions in mm

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

X2-DSN1006-3



Dimensions	Value (in mm)
G	0.30
G1	0.20
X	0.25
X1	0.70
Y	0.40
Y1	1.10

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